

EPO-TEK® H20E-175

Technical Data Sheet

For Reference Only

Electrically Conductive, Silver Epoxy

Date:	November 2019	
Rev:	VII	
No. of Components:	Two	
Mix Ratio by Weight:	1:1	
Specific Gravity:	Part A: 2.44	Part B: 3.07
Pot Life:	3.5 Days	
Shelf Life- Bulk:	One year at room temperature	

Recommended Cure: 180°C / 1 Hour

Minimum Alternative Cure(s): May not achieve performance properties listed below 150°C / 2 Hours

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description</u>: EPO-TEK® H20E-175 is a two component epoxy designed for semiconductor die-attach. It is a higher Tg version of EPO-TEK® H20E. It was designed to be used in semiconductor / JEDEC packaging, microelectronic packaging of hybrids, as well as high temperature devices and assembly.

<u>Typical Properties:</u> Cure condition: 180°C / 1 Hour Different batches, conditions & applications yield differing results. Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:			
* Color (before cure):	Part A: Silver	Part B: Silver	
* Consistency:	Smooth thixot	h thixotropic paste	
* Viscosity (23°C) @ 100 rpm:	2,800 - 3,800	cPs	
Thixotropic Index:	3.1		
* Glass Transition Temp:	≥ 85	°C (Dynamic Cure: 20-250°C/ISO 25 Min; Ramp -10-250°C @20°C/Min)	
Coefficient of Thermal Expansion (CTE):			
Belov	w Tg: 20		
Abov	re Tg: 88	x 10 ⁻⁶ in/in°C	
Shore D Hardness:	70		
Lap Shear @ 23°C:	1,292		
Die Shear @ 23°C:	≥ 10	5 / I	
Degradation Temp:	450	O° C	
Weight Loss:	_		
	0.05 OC:		
	50°C: 0.11		
	0.25 OO°C:		
Suggested Operating Temperature:			
Storage Modulus:	628,212	I	
* Particle Size:	≤ 45	microns	
ELECTRICAL AND THERMAL PROPERTIES:			
Thermal Conductivity:	2.0	W/mK	
* Volume Resistivity @ 23°C:	≤ 0.0004	Ohm-cm	



EPO-TEK[®] H20E-175 Advantages & Suggested Application Notes:

- Thixotropic paste-like rheology allows for high speed dispensing and screen printing operations. It can also be applied by hand techniques using spatula, toothpick, or stamping chuck.
- Suggested for Rf/Microwave device packaging found in military, commercial, aerospace and cockpit, and industrial (down-hole petrochemical) circuits.
- > 3 day pot-life allows for mass production yielding low waste.